

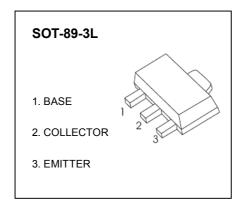
### JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

# **SOT-89-3L Plastic-Encapsulate Transistors**

BC869 TRANSISTOR (PNP)

#### **FEATURES**

- NPN Complement to BC868
- Low Voltage
- High Current



#### MAXIMUM RATINGS (T<sub>a</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-32	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-20	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
Ic	Collector Current	-1	Α
Pc	Collector Power Dissipation	500	mW
R <sub>0JA</sub>	Thermal Resistance From Junction To Ambient	250	°C/W
Tj	Junction Temperature	150	$^{\circ}$
$T_{stg}$	Storage Temperature	-55~+150	$^{\circ}$

#### **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-100μA,I <sub>E</sub> =0	-32			٧
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-1mA,I <sub>B</sub> =0	-20			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-100μA,I <sub>C</sub> =0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-25V,I <sub>E</sub> =0			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V,I <sub>C</sub> =0			-0.1	μA
	h <sub>FE(1)</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-5mA	50			
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> =-1V, I <sub>C</sub> =-0.5A	100		375	
	h <sub>FE(3)</sub>	V <sub>CE</sub> =-1V, I <sub>C</sub> =-1A	60			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-1A,I <sub>B</sub> =-0.1A			-0.5	V
Page emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> =-1V, I <sub>C</sub> =-1A			-1	٧
Base -emitter voltage		V <sub>CE</sub> =-10V, I <sub>C</sub> =-5mA		-0.62		V
Transition frequency	f⊤	VcE=-5V,Ic=-10mA, f=100MHz	40			MHz

#### **CLASSIFICATION OF h**<sub>FE(2)</sub>

RANK	BC869	BC869-16	BC869-25
RANGE	100 - 375	100 - 250	160 - 375
MARKING	CEC	CGC	СНС

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